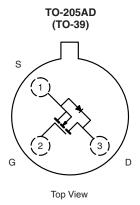
2N6660, 2N6660-2, 2N6660JANTX, 2N6660JANTXV

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N-Channel 60 V (D-S) MOSFET

PRODUCT SUMMARY					
V _{DS} (V)	60				
$R_{DS(on)}(\Omega)$ at $V_{GS} = 10 \text{ V}$	3				
Configuration	Single				



FEATURES

- Military Qualified
- Low On-Resistence: 1.3 Ω
- Low Threshold: 1.7 V
- Low Input Capacitance: 35 pF
- Fast Switching Speed: 8 ns
- Low Input and Output Leakage

BENEFITS

- · Guaranteed Reliability
- Low Offset Voltage
- Low-Voltage Operation
- Easily Driven Without Buffer
- High-Speed Circuits
- Low Error Voltage

APPLICATIONS

- Hi-Rel Systems
- Direct Logic-Level Interface: TTL/CMOS
- Drivers: Relays, Solenoids, Lamps, Hammers, Displays, Memories, Transistors, etc.
- · Battery Operated Systems
- Solid-State Relays

ORDERING INFORMATION					
PART	PACKAGE	DESCRIPTION/DSCC PART NUMBER	VISHAY ORDERING PART NUMBER		
ONICCCO		Commercial	2N6660		
2N6660		Commercial, Lead (Pb)-free	2N6660-E3		
2N6660-2		See -2 Flow Document	2N6660-2		
	TO-205AD	JANTX2N6660 (std Au leads)	2N6660JTX02		
	(TO-39)	JANTX2N6660 (with solder)	2N6660JTXL02		
		JANTX2N6660P (with PIND)	2N6660JTXP02		
2N6660JANTXV		JANTXV2N6660 (std Au leads)	2N6660JTXV02		
		JANTXV2N6660P (with PIND)	2N6660JTVP02		

ABSOLUTE MAXIMUM RATINGS ($T_A = 25 ^{\circ}C$, unless othe	rwise noted)		
PARAMETER		SYMBOL	LIMIT	UNIT
Drain-Source Voltage		V _{DS}	60	
Gate-Source Voltage		V _{GS}	± 20	V
Continuous Drain Current (T _J = 150 °C)	T _C = 25 °C	I-	0.99	
	T _C = 100 °C	I _D	0.62	A
Pulsed Drain Current ^a		I _{DM}	3	
Manine Develop Dissipation	T _C = 25 °C	В	6.25	10/
Maximum Power Dissipation	T _A = 25 °C	P _D	0.725	W
Thermal Resistance, Junction-to-Ambient ^b	ermal Resistance, Junction-to-Ambient ^b		170	°C/W
Thermal Resistance, Junction-to-Case	stance, Junction-to-Case		20	-C/W
Operating Junction and Storage Temperature Ra	ange	T _{.I} , T _{sta}	- 55 to 150	°C

Notes

- a. Pulse width limited by maximum junction temperature.
- b. Not required by military spec.



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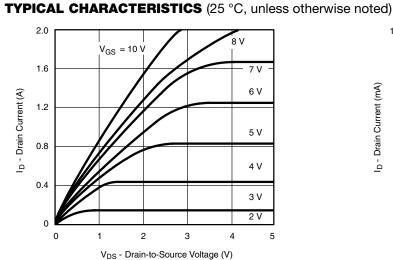
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SPECIFICATIONS (T _A = 25 °C, unless otherwise noted)									
					LIMITS				
PARAMETER	SYMBOL	TEST CONDITIONS			MIN.	TYP.a	MAX.	UNIT	
Static									
Drain-Source Breakdown Voltage	V_{DS}	$V_{DS} = 0 \text{ V}, I_{D} = 10 \mu\text{A}$		μΑ	60	75	-		
		$V_{DS} = V_{GS}$, $I_D = 1 \text{ mA}$ $T_C = -55 \text{ °C}$		0.8	1.7	2	v		
Gate-Source Threshold Voltage	V _{GS(th)}			T _C = - 55 °C	-	-	2.5	·	
				T _C = 125 °C	0.3	-	-		
Gate-Body Leakage	lana	$V_{GS} = \pm 20 \text{ V}$	V_{DS}	= 0 V	-	-	± 100	nA	
Gate-Body Leakage	I _{GSS}	VGS - ± 20 V		T _C = 125 °C	-	-	± 500		
Zero Gate Voltage Drain Current	1	V _{GS} = 0 V	V _{DS} =	= 48 V	-	-	1	μA	
Zero Gate Voltage Drain Gurrent	I _{DSS}	V _{GS} = U V		T _C = 125 °C	-	-	100	μΑ	
On-State Drain Current	I _{D(on)}	V _{GS} = 10 V	V _{DS} =	= 10 V	-	2	-	Α	
		$V_{GS} = 5 V$	$I_D =$	0.3 A	-	2	5		
Drain-Source On-State Resistanceb	R _{DS(on)}	V _{GS} = 10 V	I _D =	: 1 A	-	1.3	3	Ω	
				T _C = 125 °C	-	2.4	5.6		
Forward Transconductanceb	9 _{fs}	V _{DS} = 7.5 V, I _D = 0.525 A		170	350	-	mS		
Diode Forward Voltage	V_{SD}	I _S = 0.99 A, V _{GS} = 0 V		0.7	0.8	1.6	V		
Dynamic									
Input Capacitance	C _{iss}			-	35	50			
Output Capacitance	Coss	$V_{GS} = 0 \text{ V}$ $V_{DS} = 25 \text{ V}, f = 1 \text{ MHz}$		f _ 1 M⊔-	-	25	40	рF	
Reverse Transfer Capacitance	C _{rss}			, =	-	7	10		
Drain-Source Capacitance	C _{ds}				-	30	-		
Switching ^c									
Turn-On Time	t _{ON}		_D = 25 V, R _L = 2		-	8	10	ne	
Turn-Off Time	t _{OFF}	$I_D \cong 1 \text{ A}, V_{GEN} = 10 \text{ V}, R_g = 25 \Omega$		-	8.5	10	ns		

Notes

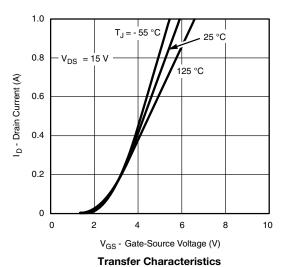
- a. FOR DESIGN AID ONLY, not subject to production testing.
- b. Pulse test: PW \leq 300 μ s duty cycle \leq 2 %.
- c. Switching time is essentially independent of operating temperature.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



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Ohmic Region Characteristics

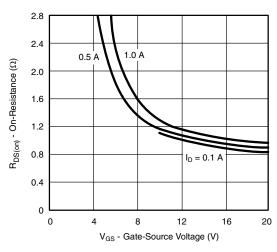


On-Resistance vs. Drain Current

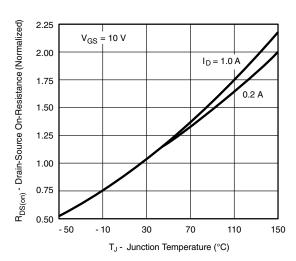
2.5

100 V_{GS} = 10 V 2.8 V 80 2.6 V I_D - Drain Current (mA) 60 40 2.2 V 20 1.8 V 2.0 V 0 0 0.4 0.8 1.2 1.6 2.0 V_{DS} - Drain-to-Source Voltage (V)

Output Characteristics for Low Gate Drive



On-Resistance vs. Gate-to-Source Voltage



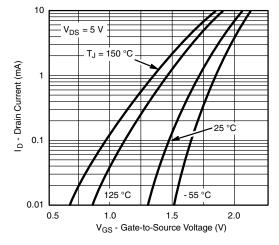
Normalized On-Resistance vs. Junction Temperature

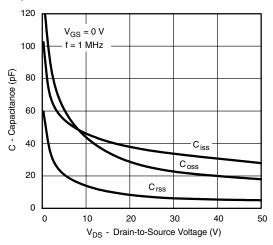
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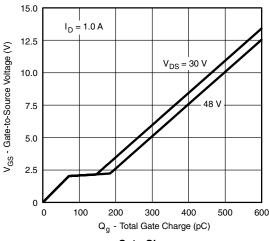
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TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)

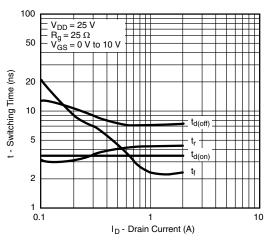




Threshold Region

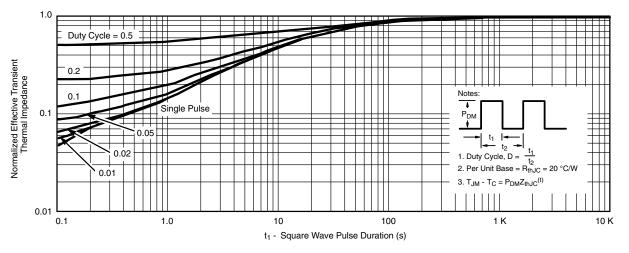


Capacitance



Gate Charge





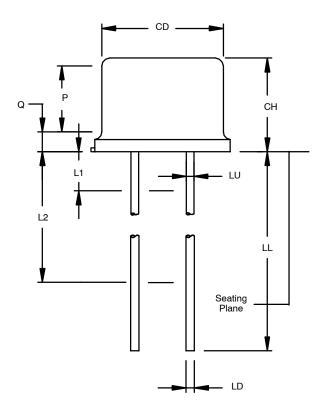
Normalized Thermal Transient Impedance, Junction-to-Ambient

Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see www.vishay.com/ppg?70223.



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TO-205AD (TO-39 TALL LID)

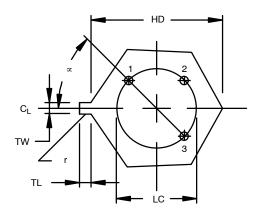


	INC	INCHES		MILLIMETERS		
Dim	Min	Max	Min	Max	Notes	
CD	0.305	0.335	7.75	8.51		
СН	0.240	0.260	6.10	6.60		
HD	0.335	0.370	8.51	9.40		
LC	0.200 TP		5.08	5.08 TP 6		
LD	0.016	0.021	0.41	0.53	7, 8	
LL	0.500	0.750	12.70	19.05	7, 8	
LU	0.016	0.019	0.41	0.48	7, 8	
L1	_	0.050	_	1.27	7, 8	
L2	0.250	_	6.35	_	7, 8	
Р	0.100	_	2.54	_	5	
Q	_	0.050	_	1.27	4	
r	_	0.010	_	0.25	9	
TL	0.029	0.045	0.74	1.14	3	
TW	0.028	0.034	0.71	0.86	2	
œ	45°	TP	45°	TP	6	

Dimensions (see notes 1, 2, 9, 11, 12)

ECN: S-40373-Rev. C, 15-Mar-04

DWG: 5511



NOTES:

- Dimensions are in inches. Metric equivalents are given for general
- Beyond radius (r) maximum, TW shall be held for a minimum length of 0.011 (0.028 mm).
- Dimension TL measured from maximum HD.
- Outline in this zone is not controlled.
- Dimension CD shall not vary more than 0.010 (0.25 mm) in zone P. This zone is controlled for automatic handling.
- Leads at guage plane 0.054+0.001, -0.000 (1.37+0.03, -0.00 mm) below seating plane shall be within 0.007 (0.18 mm) radius of true position (TP) at maximum material condition (MMC) relative to tab at MMC.
- LU applies between L1 and L2, LD applies between L2 and L maximum. Diameter is uncontrolled in L1 and beyond LL minimum.
- Radius (r) applies to both inside corners of tab.
- 10. Drain is electrically connected to the case.



Legal Disclaimer Notice

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